## LOYOLA COLLEGE (AUTONOMOUS), CHENNAI - 600 034

**B.Sc.**DEGREE EXAMINATION –**PHYSICS** 

FOURTH SEMESTER - APRIL 2018

### PH 4506- ELECTRONICS - I

 $\underline{PART} - \underline{A}$ 

Date: 09-05-2018 Time: 09:00-12:00 Dept. No.

Max.: 100 Marks

# Answer All Questions.

(10 X 2 = 20 MARKS)

 $(4 \times 7.5 = 30 \text{ marks})$ 

- 1. State Superposition Theorem.
- 2. What is a linear network?
- 3. Write the Barkhausen criterion for oscillation in oscillators.
- 4. Draw the circuit of a transistor biased using a voltage divider network.
- 5. Define open loop gain of an op-amp.
- 6. Define CMRR. Give its value for an ideal and practical op-amp.
- 7. Write the three basic laws of Boolean algebra.
- 8. Draw the block diagram of a 4-input multiplexer and give its function table.
- 9. Write the classification of ICs based on the techniques used in manufacturing them.
- 10. What are hybrid integrated circuits? State is significant features.

### <u>PART – B</u>

#### Answer ANY FOUR Questions.

- 11. State and explain Thevenin's theorem.
- 12. Explain the working of a phase shift oscillator and obtain its frequency of oscillation.
- 13. Explain with the necessary circuit the working of an op-amp subtractor.
- 14. Explain the working of a JK flip-flop and give the truth table.
- 15. Describe the construction of a 1-line to 4-line demultiplexer using logic gates and explain its function table.
- 16. Explain the fabrication of monolithic Integrated Circuits.

Answer ANY FOUR questions	PART C	(4 x 12.5 = 50 marks)
17. Obtain expressions for Ai, Av and Ziinterms of 'h'parameters for a transistor amplifier connected in		
common emitter configuration	n with necessary equivalent circuit.	
18. (a) Explain with a neat circui	t the functioning of a direct coupled	amplifier.
(b) Discuss the working of a	transistor Monostablemultivibrator.	(6.5+6)
19. Discuss the construction and operation of a depletion type MOSFET and explain its drain and		
transfer characteristics.		
20. (a) Explain the working of a f	our bit shift right shift register.	
(b) Explain the two types of F	Random Access Memory.	(6.5+6)
21. Differentiate between asynchronous and synchronous counters. Draw the circuit of a 3-bit ripple		
counter and explain its working	ng.	(2.5+10)
22. Explain with necessary diagrams the fabrication of transistors and diodes on monolithic Integrated		
Circuits.	(6.5+6)	

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